

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7MH157FK

## Quad 2-Channel Multiplexer

The TC7MH157FK is an advanced high speed CMOS quad 2-channel multiplexer fabricated with silicon gate C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

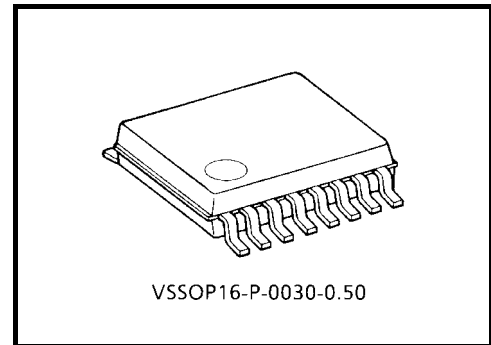
It consists of four 2-input digital multiplexers with common select and strobe inputs.

When the strobe input ( $\overline{ST}$ ) is held "H" level, selection of data is inhibited and all the outputs become "L" level.

The SELECT decoding determines whether the A or B inputs get routed to their corresponding Y outputs.

An Input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage.

This device can be used to interface 5 V to 3 V systems and on two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

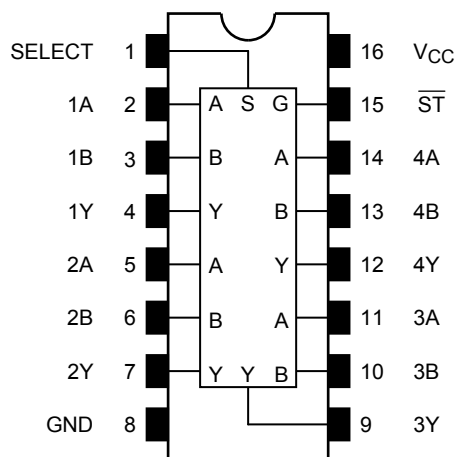


Weight: 0.02 g (typ.)

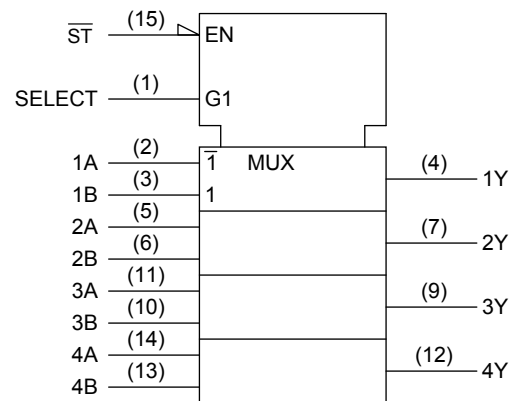
## Features

- High speed:  $t_{pd} = 4.1 \text{ ns (typ.) (} V_{CC} = 5 \text{ V)}$
- Low power dissipation:  $I_{CC} = 4 \mu\text{A (max) (} T_a = 25^\circ\text{C)}$
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC} \text{ (min)}$
- Power down protection is provided on all inputs.
- Balanced propagation delays:  $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range:  $V_{CC} \text{ (opr)} = 2\sim 5.5 \text{ V}$
- Low noise:  $V_{OLP} = 0.8 \text{ V (max)}$
- Pin and function compatible with 74ALS157

## Pin Assignment (top view)



## IEC Logic Symbol

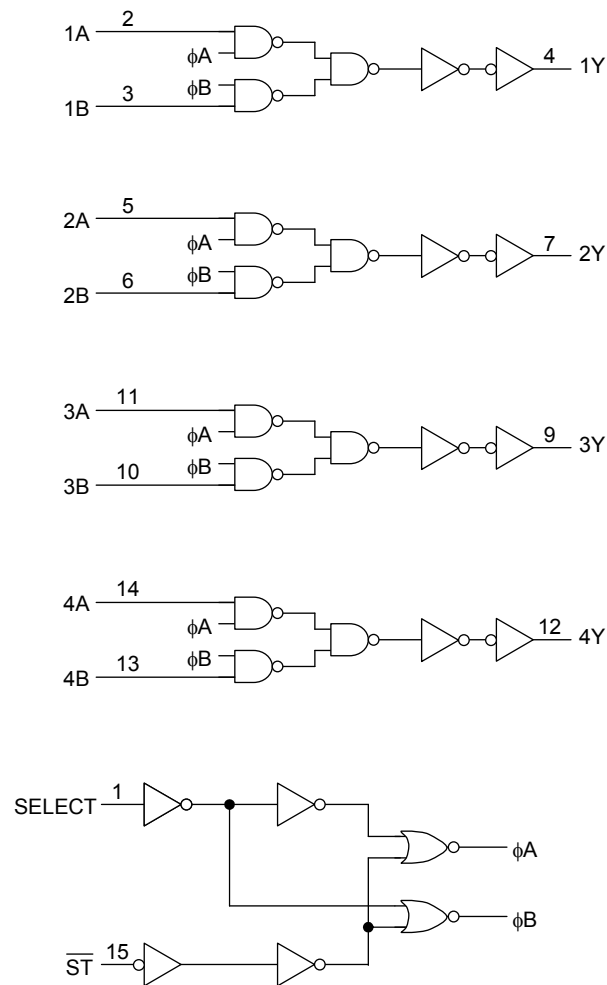


## Truth Table

Inputs				Outputs
ST-bar	Select	A	B	
H	X	X	X	L
L	L	L	X	L
L	L	H	X	H
L	H	X	L	L
L	H	X	H	H

X: Don't care

## System Diagram



## Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	$V_{CC}$	-0.5~7.0	V
DC input voltage	$V_{IN}$	-0.5~7.0	V
DC output voltage	$V_{OUT}$	-0.5~ $V_{CC} + 0.5$	V
Input diode current	$I_{IK}$	-20	mA
Output diode current	$I_{OK}$	$\pm 20$	mA
DC output current	$I_{OUT}$	$\pm 25$	mA
DC $V_{CC}$ /ground current	$I_{CC}$	$\pm 50$	mA
Power dissipation	$P_D$	180	mW
Storage temperature	$T_{stg}$	-65~150	$^{\circ}C$

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	$V_{CC}$	2.0~5.5	V
Input voltage	$V_{IN}$	0~5.5	V
Output voltage	$V_{OUT}$	0~ $V_{CC}$	V
Operating temperature	$T_{opr}$	-40~85	°C
Input rise and fall time	dt/dv	0~100 ( $V_{CC} = 3.3 \pm 0.3$ V)	ns/V
		0~20 ( $V_{CC} = 5 \pm 0.5$ V)	

Note: The operating ranges must be maintained to ensure the normal operation of the device.  
Unused inputs must be tied to either VCC or GND.

## Electrical Characteristics

### DC Characteristics

Characteristics		Symbol	Test Condition	Ta = 25°C			Ta = -40~85°C		Unit			
				V <sub>CC</sub> (V)	Min	Typ.	Max	Min		Max		
Input voltage	High level	$V_{IH}$	—	2.0	1.50	—	—	1.50	—	V		
				3.0~5.5	$V_{CC} \times 0.7$	—	—	$V_{CC} \times 0.7$	—			
	Low level	$V_{IL}$		2.0	—	—	0.50	—	0.50			
				3.0~5.5	—	—	$V_{CC} \times 0.3$	—	$V_{CC} \times 0.3$			
Output voltage	High level	$V_{OH}$	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OH} = -50 \mu A$	2.0	1.9	2.0	—	1.9	—	V	
					3.0	2.9	3.0	—	2.9	—		
					4.5	4.4	4.5	—	4.4	—		
				$I_{OH} = -4$ mA	3.0	2.58	—	—	2.48	—		
					4.5	3.94	—	—	3.80	—		
	Low level	$V_{OL}$		$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 50 \mu A$	2.0	—	0	0.1	—		0.1
						3.0	—	0	0.1	—		0.1
						4.5	—	0	0.1	—		0.1
					$I_{OL} = 4$ mA	3.0	—	—	0.36	—		0.44
						4.5	—	—	0.36	—		0.44
Input leakage current		$I_{IN}$	$V_{IN} = 5.5$ V or GND	0~5.5	—	—	±0.1	—	±1.0	μA		
Quiescent supply current		$I_{CC}$	$V_{IN} = V_{CC}$ or GND	5.5	—	—	4.0	—	40.0	μA		

## AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40~85°C		Unit		
			V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Typ.	Max		Min	Max
Propagation delay time (A, B-Y)	$t_{pLH}$ $t_{pHL}$	—	3.3 ± 0.3	15	—	6.2	9.7	1.0	11.5	ns
				50	—	8.7	13.2	1.0	15.0	
			5.0 ± 0.5	15	—	4.1	6.4	1.0	7.5	
				50	—	5.6	8.4	1.0	9.5	
Propagation delay time (SELECT-Y)	$t_{pLH}$ $t_{pHL}$	—	3.3 ± 0.3	15	—	8.4	13.2	1.0	15.5	ns
				50	—	10.9	16.7	1.0	19.0	
			5.0 ± 0.5	15	—	5.3	8.1	1.0	9.5	
				50	—	6.8	10.1	1.0	11.5	
Propagation delay time ( $\overline{ST}$ -Y)	$t_{pLH}$ $t_{pHL}$	—	3.3 ± 0.3	15	—	8.7	13.6	1.0	16.0	ns
				50	—	11.2	17.1	1.0	19.5	
			5.0 ± 0.5	15	—	5.6	8.6	1.0	10.0	
				50	—	7.1	10.6	1.0	12.0	
Input capacitance	C <sub>IN</sub>	—	—	—	4	10	—	10	pF	
Power dissipation capacitance	C <sub>PD</sub>	(Note)			—	20	—	—	—	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

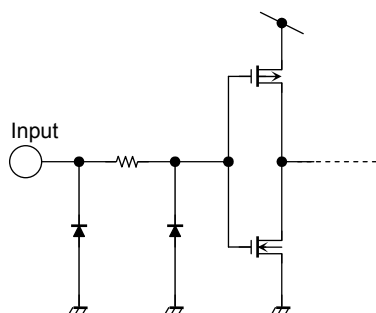
Average operating current can be obtained by the equation:

$$I_{CC(\text{opr})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per bit)}$$

## Noise Characteristics (Input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	Test Condition	Ta = 25°C			Unit
			V <sub>CC</sub> (V)	Typ.	Limit	
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	5.0	0.3	0.8	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-0.3	-0.8	V
Minimum high level dynamic input voltage V <sub>IH</sub>	V <sub>IHD</sub>	C <sub>L</sub> = 50 pF	5.0	—	3.5	V
Maximum low level dynamic input voltage V <sub>IL</sub>	V <sub>ILD</sub>	C <sub>L</sub> = 50 pF	5.0	—	1.5	V

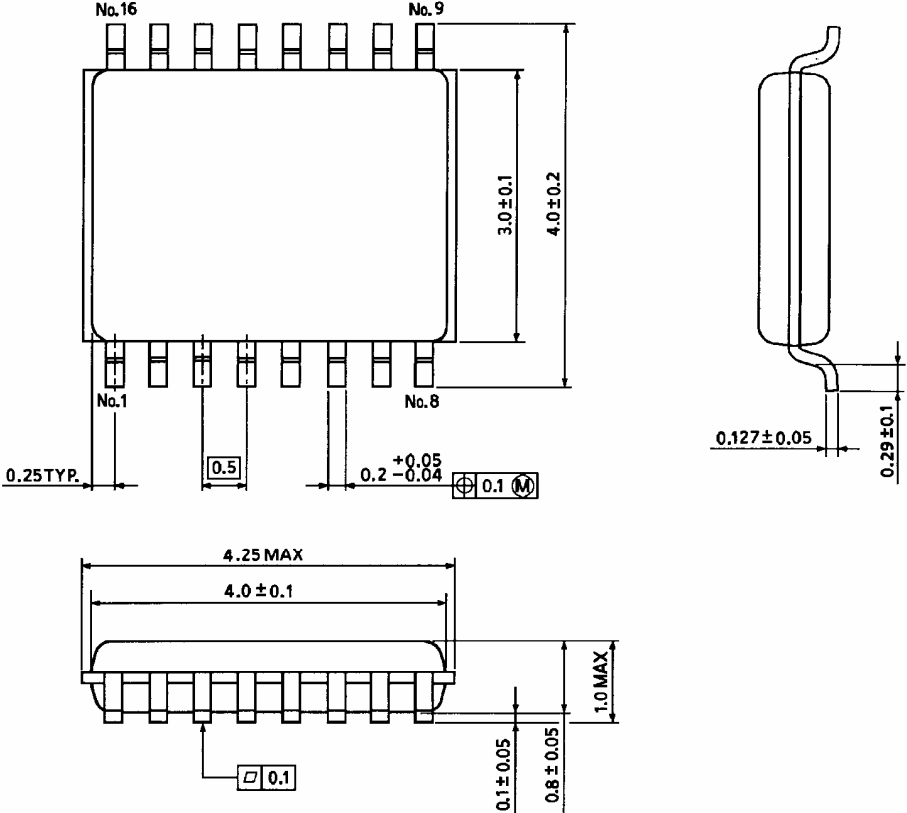
## Input Equivalent Circuit



Package Dimensions

VSSOP16-P-0030-0.50

Unit : mm



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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